

FIFTEEN OUTPUT DIFFERENTIAL ZBUFFER FOR PCIE GEN2/3 AND QPI

9ZX21501C

Description

The 9ZX21501C is a 15-output version of the Intel DB1900Z Differential Buffer suitable for PCI-Express Gen3 or QPI applications. The part is backwards compatible to PCIe Gen1 and Gen2. A fixed external feedback maintains low drift for critical QPI applications. In bypass mode, the 9ZX21501C can provide outputs up to 400MHz.

Recommended Application

15-output PCIe Gen3/QPI buffer with fixed feedback for Romley platforms

Output Features

15 - 0.7V current mode differential HCSL output pairs

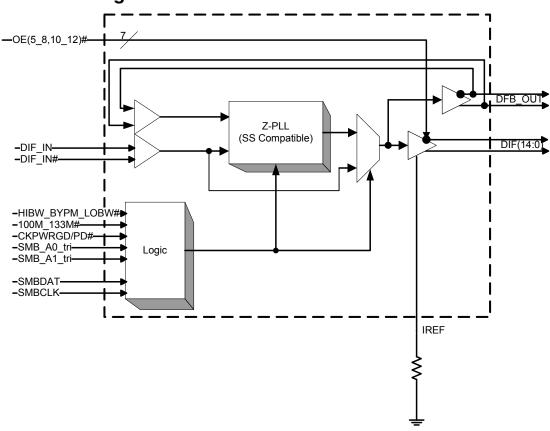
Features/Benefits

- Fixed feedback path; Ops input-to-output delay
- 9 Selectable SMBus addresses; multiple devices can share same SMBus segment
- 7 dedicated OE# pins; hardware control of outputs
- PLL or bypass mode; PLL can dejitter incoming clock
- Selectable PLL BW; minimizes jitter peaking in downstream PLL's
- Spread spectrum compatible; tracks spreading input clock for EMI reduction
- SMBus Interface; unused outputs can be disabled
- 100MHz & 133.33MHz PLL mode; legacy QPI support
- Undriven differential outputs in Power Down mode for maximum power savings

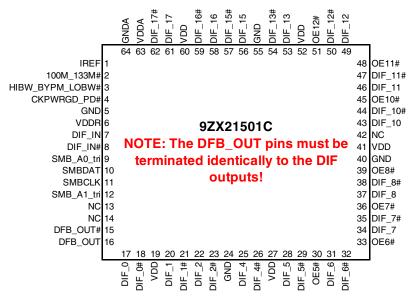
Key Specifications

- Cycle-to-cycle jitter: <50ps
- Output-to-output skew: <65ps
- Input-to-output delay: Fixed at 0 ps
- Input-to-output delay variation: <50ps
- Phase jitter: PCle Gen3 <1ps rms
- Phase jitter: QPI 9.6GB/s <0.2ps rms

Functional Block Diagram



Pin Configuration



Power Management Table

Inputs	Control Bits/Pins				Outputs	B	
CKPWRGD•/PD#	DIF_IN/ DIF_IN#					DFB_OUT/ DFB_OUT#	PLL State
0	Х	Х	Х	Hi-Z ¹	Hi-Z ¹	Hi-Z ¹	OFF
		0	Х	Hi-Z ¹	Hi-Z ¹	Running	ON
1	Running	1	0	Running	Running	Running	ON
		1	1	Hi-7 ¹	Running	Runnina	ON

NOTE 1: Due to external pull down resistors, HI-Z results in Low/Low on the True/Complement outputs

Functionality at Power-up (PLL mode)

100M_133M#	DIF_IN (MHz)	DIF MHz		
1	100.00	DIF_IN		
0	133.33	DIF_IN		

PLL Operating Mode

HiBW_BypM_LoBW#	MODE
Low	PLL Lo BW
Mid	Bypass
High	PLL Hi BW

NOTE: PLL is OFF in Bypass Mode

PLL Operating Mode Readback Table

HiBW_BypM_LoBW#	Byte0, bit 7	Byte 0, bit 6
Low (Low BW)	0	0
Mid (Bypass)	0	1
High (High BW)	1	1

Tri-Level Input Thresholds

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Level	Voltage
Low	<0.8V
Mid	1.2 <vin<1.8v< td=""></vin<1.8v<>
High	Vin > 2.2V

Power Connections

Pin Nu	Pin Number					
VDD	GND	Description				
63	64	Analog PLL				
6	5	Input Circuit				
19, 27, 41, 52, 60	24, 40, 55	DIF clocks				

SMBus Addressing

Piı	n	SMBus Address
SMB_A1_tri	SMB_A0_tri	(Rd/Wrt bit = 0)
0	0	D8
0	М	DA
0	1	DE
M	0	C2
M	М	C4
М	1	C6
1	0	CA
1	М	CC
1	1	CE

Pin Descriptions

PIN#	PIN NAME	TYPE	DESCRIPTION
			This pin establishes the reference for the differential current-mode output pairs. It requires a fixed precision
1	IREF	OUT	resistor to ground. 475ohm is the standard value for 100ohm differential impedance. Other impedances
			require different values. See data sheet.
2	100M_133M#	IN	3.3V Input to select operating frequency
	100IVI_100IVI#	IIN	See Functionality Table for Definition
3	HIBW_BYPM_LOBW#	IN	Trilevel input to select High BW, Bypass or Low BW mode.
- 0	TIIDVV_DTT IVI_LODVV#	IIN	See PLL Operating Mode Table for Details.
4	CKPWRGD PD#	IN	Notifies device to sample latched inputs and start up on first high assertion, or exit Power Down Mode on
_	OR WIND_I D#	111	subsequent assertions. Low enters Power Down Mode.
5	GND	PWR	Ground pin.
6	VDDR	PWR	3.3V power for differential input clock (receiver). This VDD should be treated as an analog power rail and filtered appropriately.
7	DIF_IN	IN	0.7 V Differential TRUE input
8	DIF_IN#	IN	0.7 V Differential Complementary Input
9	SMB_A0_tri	IN	SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A1 to decode 1 of 9 SMBus Addresses.
10	SMBDAT	I/O	Data pin of SMBUS circuitry, 5V tolerant
11	SMBCLK	IN	Clock pin of SMBUS circuitry, 5V tolerant
40			SMBus address bit. This is a tri-level input that works in conjunction with the SMB_A0 to decode 1 of 9
12	SMB_A1_tri	IN	SMBus Addresses.
13	NC	N/A	No Connection.
14	NC	N/A	No Connection.
15	DER OUT#	OUT	Complementary half of differential feedback output, provides feedback signal to the PLL for
15	DFB_OUT#	001	synchronization with input clock to eliminate phase error.
16	DFB_OUT	OUT	True half of differential feedback output, provides feedback signal to the PLL for synchronization with the
16	DFB_001	001	input clock to eliminate phase error.
17	DIF_0	OUT	0.7V differential true clock output
18	DIF_0#	OUT	0.7V differential Complementary clock output
19	VDD	PWR	Power supply, nominal 3.3V
20	DIF_1	OUT	0.7V differential true clock output
21	DIF_1#	OUT	0.7V differential Complementary clock output
22	DIF_2	OUT	0.7V differential true clock output
23	DIF_2#	OUT	0.7V differential Complementary clock output
24	GND	PWR	Ground pin.
25	DIF_4	OUT	0.7V differential true clock output
26	DIF_4#	OUT	0.7V differential Complementary clock output
27	VDD	PWR	Power supply, nominal 3.3V
28	DIF_5	OUT	0.7V differential true clock output
29	DIF_5#	OUT	0.7V differential Complementary clock output
30	OE5#	IN	Active low input for enabling DIF pair 5. 1 =disable outputs, 0 = enable outputs
31	DIF_6	OUT	0.7V differential true clock output
32	DIF_6#	OUT	0.7V differential Complementary clock output
33	OE6#	IN	Active low input for enabling DIF pair 6.
- 55		IIN	1 =disable outputs, 0 = enable outputs
34	DIF_7	OUT	0.7V differential true clock output
35	DIF_7#	OUT	0.7V differential Complementary clock output
36	OE7#	IN	Active low input for enabling DIF pair 7.
	02711		1 =disable outputs, 0 = enable outputs

Pin Descriptions (continued)

37	DIF_8	OUT	0.7V differential true clock output
38	DIF_8#	OUT	0.7V differential Complementary clock output
39	OE8#	IN	Active low input for enabling DIF pair 8.
39	OL0#	IIN	1 =disable outputs, 0 = enable outputs
40	GND	PWR	Ground pin.
41	VDD	PWR	Power supply, nominal 3.3V
42	NC	N/A	No Connection.
43	DIF_10	OUT	0.7V differential true clock output
44	DIF_10#	OUT	0.7V differential Complementary clock output
45	OE10#	IN	Active low input for enabling DIF pair 10.
43	OL 10#	IIN	1 =disable outputs, 0 = enable outputs
46	DIF_11	OUT	0.7V differential true clock output
47	DIF_11#	OUT	0.7V differential Complementary clock output
48	OE11#	IN	Active low input for enabling DIF pair 11.
40	OE11#	IIN	1 =disable outputs, 0 = enable outputs
49	DIF_12	OUT	0.7V differential true clock output
50	DIF_12#	OUT	0.7V differential Complementary clock output
51	OE12#	IN	Active low input for enabling DIF pair 12.
31	OL 12#	IIN	1 =disable outputs, 0 = enable outputs
52	VDD	PWR	Power supply, nominal 3.3V
53	DIF_13	OUT	0.7V differential true clock output
54	DIF_13#	OUT	0.7V differential Complementary clock output
55	GND	PWR	Ground pin.
56	DIF_15	OUT	0.7V differential true clock output
57	DIF_15#	OUT	0.7V differential Complementary clock output
58	DIF_16	OUT	0.7V differential true clock output
59	DIF_16#	OUT	0.7V differential Complementary clock output
60	VDD		Power supply, nominal 3.3V
61	DIF_17	OUT	0.7V differential true clock output
62	DIF_17#	OUT	0.7V differential Complementary clock output
63	VDDA	PWR	3.3V power for the PLL core.
64	GNDA	PWR	Ground pin for the PLL core.

Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the 9ZX21501C. These ratings, which are standard values for IDT commercially rated parts, are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
3.3V Core Supply Voltage	VDDA				4.6	V	1,2
3.3V Logic Supply Voltage	VDD				4.6	V	1,2
Input Low Voltage	V_{IL}		GND-0.5			V	1
Input High Voltage	V_{IH}	Except for SMBus interface			V _{DD} +0.5V	V	1
Input High Voltage	V _{IHSMB}	SMBus clock and data pins			5.5V	٧	1
Storage Temperature	Ts		-65		150	°C	1
Junction Temperature	Tj				125	°C	1
Input ESD protection	ESD prot	Human Body Model	2000			٧	1

¹Guaranteed by design and characterization, not 100% tested in production.

Electrical Characteristics-Clock Input Parameters

TA = T_{COM}. Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Input High Voltage - DIF_IN	V _{IHDIF}	Differential inputs (single-ended measurement)	600	750	1150	mV	1
Input Low Voltage - DIF_IN	V _{ILDIF}	Differential inputs (single-ended measurement)	V _{SS} - 300	0	300	mV	1
Input Common Mode Voltage - DIF_IN	V_{COM}	Common Mode Input Voltage	300		1000	mV	1
Input Amplitude - DIF_IN	V_{SWING}	Peak to Peak value	300		1450	mV	1
Input Slew Rate - DIF_IN	dv/dt	Measured differentially	0.4		8	V/ns	1,2
Input Leakage Current	I _{IN}	$V_{IN} = V_{DD}$, $V_{IN} = GND$	-5		5	uA	1
Input Duty Cycle	d _{tin}	Measurement from differential wavefrom	45		55	%	1
Input Jitter - Cycle to Cycle	J_{DIFIn}	Differential Measurement	0		125	ps	1

¹ Guaranteed by design and characterization, not 100% tested in production.

² Operation under these conditions is neither implied nor guaranteed.

²Slew rate measured through +/-75mV window centered around differential zero

Electrical Characteristics-Input/Supply/Common Output Parameters

 $TA = T_{COM}$; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

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PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Ambient Operating Temperature	ТСОМ	Commmercial range	0		70	°C	1
Input High Voltage	V _{IH}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	2		V _{DD} + 0.3	V	1
Input Low Voltage	V_{IL}	Single-ended inputs, except SMBus, low threshold and tri-level inputs	GND - 0.3		0.8	٧	1
	I _{IN}	Single-ended inputs, $V_{IN} = GND$, $V_{IN} = VDD$	-5		5	uA	1
Input Current	I _{INP}	$\label{eq:VIN} Single-ended inputs \\ V_{IN} = 0 \ V; \ Inputs \ with internal \ pull-up \ resistors \\ V_{IN} = VDD; \ Inputs \ with \ internal \ pull-down \ resistors$	-200		200	uA	1
	F_{ibyp}	V _{DD} = 3.3 V, Bypass mode	33		400	MHz	2
Input Frequency	F_{ipll}	$V_{DD} = 3.3 \text{ V}, 100\text{MHz PLL mode}$	90	100.00	105	MHz	2
	F_{ipll}	V _{DD} = 3.3 V, 133.33MHz PLL mode	120	133.33	140	MHz	2
Pin Inductance	L_{pin}				7	nΗ	1
	C_{IN}	Logic Inputs, except DIF_IN	1.5		5	pF	1
Capacitance	C _{INDIF_IN}	DIF_IN differential clock inputs	1.5		2.7	pF	1,4
	C_{OUT}	Output pin capacitance			6	pF	1
Clk Stabilization	T _{STAB}	From V _{DD} Power-Up and after input clock stabilization or de-assertion of PD# to 1st clock			1.8	ms	1,2
Input SS Modulation Frequency	f _{MODIN}	Allowable Frequency (Triangular Modulation)	30		33	kHz	1
OE# Latency	t _{LATOE#}	DIF start after OE# assertion DIF stop after OE# deassertion	4		12	clocks	1,3
Tdrive_PD#	t _{DRVPD}	DIF output enable after PD# de-assertion			300	us	1,3
Tfall	t _F	Fall time of control inputs			5	ns	1,2
Trise	t _R	Rise time of control inputs			5	ns	1,2
SMBus Input Low Voltage	V_{ILSMB}				0.8	V	1
SMBus Input High Voltage	V_{IHSMB}		2.1		V_{DDSMB}	V	1
SMBus Output Low Voltage	V_{OLSMB}	@ I _{PULLUP}			0.4	V	1
SMBus Sink Current	I _{PULLUP}	@ V _{OL}	4			mA	1
Nominal Bus Voltage	V_{DDSMB}	3V to 5V +/- 10%	2.7		5.5	V	1
SCLK/SDATA Rise Time	t _{RSMB}	(Max VIL - 0.15) to (Min VIH + 0.15)			1000	ns	1
SCLK/SDATA Fall Time	t _{FSMB}	(Min VIH + 0.15) to (Max VIL - 0.15)			300	ns	1
SMBus Operating Frequency	f _{MAXSMB}	Maximum SMBus operating frequency			100	kHz	1,5

¹Guaranteed by design and characterization, not 100% tested in production.

²Control input must be monotonic from 20% to 80% of input swing.

³Time from deassertion until outputs are >200 mV

⁴ DIF_IN input

⁵The differential input clock must be running for the SMBus to be active

Electrical Characteristics-DIF 0.7V Current Mode Differential Outputs

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Slew rate	Trf	Scope averaging on	1	2.5	4	V/ns	1, 2, 3
Slew rate matching	ΔTrf	Slew rate matching, Scope averaging on			20	%	1, 2, 4
Voltage High	VHigh	Statistical measurement on single-ended signal using oscilloscope math function. (Scope	660	750	850	mV	1
Voltage Low	VLow	averaging on)	-150		150	IIIV	1
Max Voltage	Vmax	Measurement on single ended signal using			1150	mV	1
Min Voltage	Vmin	absolute value. (Scope averaging off)	-300			IIIV	1
Vswing	Vswing	Scope averaging off	300			mV	1, 2
Crossing Voltage (abs)	Vcross_abs	Scope averaging off	250		550	mV	1, 5
Crossing Voltage (var)	Δ-Vcross	Scope averaging off			140	mV	1, 6

¹Guaranteed by design and characterization, not 100% tested in production. IREF = VDD/(3xR_R). For R_R = 475Ω (1%), I_{REF} = 2.32mA. I_{OH} = 6 x I_{REF} and V_{OH} = 0.7V @ Z_O =50Ω (100Ω differential impedance).

Electrical Characteristics—Current Consumption

 $TA = T_{COM}$; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
Operating Supply Current	I _{DD3.3OP}	All outputs active @100MHz, C _L = Full load;		390	425	mA	1
Powerdown Current	I _{DD3.3PDZ}	All differential pairs tri-stated		5	15	mA	1

¹Guaranteed by design and characterization, not 100% tested in production.

² Measured from differential waveform

³ Slew rate is measured through the Vswing voltage range centered around differential 0V. This results in a +/-150mV window around differential 0V.

⁴ Matching applies to rising edge rate for Clock and falling edge rate for Clock#. It is measured using a +/-75mV window centered on the average cross point where Clock rising meets Clock# falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations.

⁵ Vcross is defined as voltage where Clock = Clock# measured on a component test board and only applies to the differential rising edge (i.e. Clock rising and Clock# falling).

⁶ The total variation of all Vcross measurements in any particular system. Note that this is a subset of V_cross_min/max (V_cross absolute) allowed. The intent is to limit Vcross induced modulation by setting V_cross_delta to be smaller than V_cross absolute.

Electrical Characteristics-Skew and Differential Jitter Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	NOTES
CLK_IN, DIF[x:0]	t _{SPO_PLL}	Input-to-Output Skew in PLL mode nominal value @ 25°C, 3.3V	-100	0	100	ps	1,2,4,5,8
CLK_IN, DIF[x:0]	t _{PD_BYP}	Input-to-Output Skew in Bypass mode nominal value @ 25°C, 3.3V	2.5	3.5	4.5	ns	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSPO_PLL}	Input-to-Output Skew Varation in PLL mode across voltage and temperature	-50	0	50	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSPO_BYP}	Input-to-Output Skew Varation in Bypass mode across voltage and temperature	-250	0	250	ps	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DTE}	Random Differential Tracking error beween two 9ZX devices in Hi BW Mode		3	5	ps (rms)	1,2,3,5,8
CLK_IN, DIF[x:0]	t _{DSSTE}	Random Differential Spread Spectrum Tracking error beween two 9ZX devices in Hi BW Mode		15	75	ps	1,2,3,5,8
DIF{x:0]	t _{SKEW_ALL}	Output-to-Output Skew across all outputs (Common to Bypass and PLL mode)		37	65	ps	1,2,3,8
PLL Jitter Peaking	jpeak-hibw	LOBW#_BYPASS_HIBW = 1	0	1.3	2.5	dB	7,8
PLL Jitter Peaking	jpeak-lobw	LOBW#_BYPASS_HIBW = 0	0	0.8	2	dB	7,8
PLL Bandwidth	pll _{HIBW}	LOBW#_BYPASS_HIBW = 1	2	3	4	MHz	8,9
PLL Bandwidth	pll _{LOBW}	LOBW#_BYPASS_HIBW = 0	0.7	1.1	1.4	MHz	8,9
Duty Cycle	t _{DC}	Measured differentially, PLL Mode	45	50	55	%	1
Duty Cycle Distortion	t _{DCD}	Measured differentially, Bypass Mode @100MHz	-2	0	2	%	1,10
Jitter, Cycle to cycle	t:	PLL mode		41	50	ps	1,11
ontor, cyolo to cyolo	t _{jcyc-cyc}	Additive Jitter in Bypass Mode		20	50	ps	1,11

Notes for preceding table:

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9ZX21501C

¹ Measured into fixed 2 pF load cap. Input to output skew is measured at the first output edge following the corresponding input.

² Measured from differential cross-point to differential cross-point. This parameter can be tuned with external feedback path, if present.

³ All Bypass Mode Input-to-Output specs refer to the timing between an input edge and the specific output edge created by it.

⁴ This parameter is deterministic for a given device

⁵ Measured with scope averaging on to find mean value. DIF_IN slew rate must be matched to DIF output slew rate.

⁶.t is the period of the input clock

⁷ Measured as maximum pass band gain. At frequencies within the loop BW, highest point of magnification is called PLL jitter peaking.

^{8.} Guaranteed by design and characterization, not 100% tested in production.

⁹ Measured at 3 db down or half power point.

¹⁰ Duty cycle distortion is the difference in duty cycle between the output and the input clock when the device is operated in bypass mode

¹¹ Measured from differential waveform

Electrical Characteristics-Phase Jitter Parameters

TA = T_{COM}; Supply Voltage VDD/VDDA = 3.3 V +/-5%, See Test Loads for Loading Conditions

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	Notes
	t _{jphPCleG1}	PCIe Gen 1		39	86	ps (p-p)	1,2,3
	t _{iphPCleG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		1.1	3	ps (rms)	1,2
	урпРогед2	PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		2.6	3.1	ps (rms)	1,2
Jitter, Phase	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.6	1	ps (rms)	1,2,4
		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.36	0.5	ps (rms)	1,5
	t _{jphQPI_SMI}	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.23	0.3	ps (rms)	1,5
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.18	0.2	ps (rms)	1,5
	t _{jphPCleG1}	PCIe Gen 1		4	10	ps (p-p)	1,2,3
	t _{jphPCleG2}	PCIe Gen 2 Lo Band 10kHz < f < 1.5MHz		0.25	0.3	ps (rms)	1,2,6
		PCIe Gen 2 High Band 1.5MHz < f < Nyquist (50MHz)		0.57	0.7	ps (rms)	1,2,6
Additive Phase Jitter, Bypass mode	t _{jphPCleG3}	PCIe Gen 3 (PLL BW of 2-4MHz, CDR = 10MHz)		0.20	0.3	ps (rms)	1,2,4,6
Bypass mode		QPI & SMI (100MHz or 133MHz, 4.8Gb/s, 6.4Gb/s 12UI)		0.22	0.3	ps (rms)	1,5,6
	t _{jphQPI_SMI}	QPI & SMI (100MHz, 8.0Gb/s, 12UI)		0.08	0.1	ps (rms)	1,5,6
		QPI & SMI (100MHz, 9.6Gb/s, 12UI)		0.08	0.1	ps (rms)	1,5,6

¹ Applies to all outputs.

² See http://www.pcisig.com for complete specs

³ Sample size of at least 100K cycles. This figures extrapolates to 108ps pk-pk @ 1M cycles for a BER of 1-12.

⁴ Subject to final ratification by PCI SIG.

 $^{^{5}}$ Calculated from Intel-supplied Clock Jitter Tool v 1.6.3

⁶ For RMS figures, additive jitter is calculated by solving the following equation: (Additive jitter)^2 = (total jitter)^2 - (input jitter)^2

Clock Periods-Differential Outputs with Spread Spectrum Disabled

				Mea	surement Wi	ndow				
	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock		
SSC OFF	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units 1	Notes
DIF	100.00	9.94900		9.99900	10.00000	10.00100		10.05100	ns	1,2,3
DIF	133.33	7.44925		7.49925	7.50000	7.50075		7.55075	ns	1,2,4

Clock Periods-Differential Outputs with Spread Spectrum Enabled

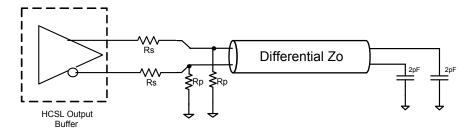
				Measurement Window								
SSC ON	Contor	1 Clock	1us	0.1s	0.1s	0.1s	1us	1 Clock				
	SSC ON	Center Freq. MHz	-c2c jitter AbsPer Min	-SSC Short-Term Average Min	- ppm Long-Term Average Min	0 ppm Period Nominal	+ ppm Long-Term Average Max	+SSC Short-Term Average Max	+c2c jitter AbsPer Max	Units	Notes	
	DIF	99.75	9.94906	9.99906	10.02406	10.02506	10.02607	10.05107	10.10107	ns	1,2,3	
	יווט.	133.00	7.44930	7.49930	7.51805	7.51880	7.51955	7.53830	7.58830	ns	1,2,4	

Notes:

Differential Output Termination Table

DIF Zo (Ω)	Iref (Ω)	Rs (Ω)	Rp (Ω)
100	475	33	50
85	412	27	42.2 or 43.2

9ZX21501 Differential Test Loads



¹Guaranteed by design and characterization, not 100% tested in production.

² All Long Term Accuracy specifications are guaranteed with the assumption that the input clock complies with CK420BQ/CK410B+ accuracy requirements (+/-100ppm). The 9ZX21501 itself does not contribute to ppm error.

³ Driven by SRC output of main clock, 100 MHz PLL Mode or Bypass mode

⁴ Driven by CPU output of main clock, 133 MHz PLL Mode or Bypass mode

General SMBus Serial Interface Information for 9ZX21501C

How to Write

- · Controller (host) sends a start bit
- Controller (host) sends the write address
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- Controller (host) sends the byte count = X
- IDT clock will acknowledge
- Controller (host) starts sending Byte N through Byte N+X-1
- IDT clock will acknowledge each byte one at a time
- Controller (host) sends a Stop bit

	Index Blo	ock '	Write Operation
Controll	er (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave Add	ress XX _(H)		
WR	WRite		
			ACK
Beginning	g Byte = N		
			ACK
Data Byte	Count = X		
			ACK
Beginnin	g Byte N		
			ACK
0		×	
0		X Byte	0
0		e.	0
			0
Byte N	+ X - 1		
			ACK
Р	stoP bit		

Note: XX_(H) is defined by SMBus addess select pins.

How to Read

- · Controller (host) will send a start bit
- Controller (host) sends the write address XX_(H)
- IDT clock will acknowledge
- Controller (host) sends the beginning byte location = N
- IDT clock will acknowledge
- · Controller (host) will send a separate start bit
- Controller (host) sends the read address YY_(H)
- IDT clock will acknowledge
- IDT clock will send the data byte count = X
- IDT clock sends Byte N+X-1
- IDT clock sends Byte 0 through Byte X (if X_(H) was written to Byte 8)
- Controller (host) will need to acknowledge each byte
- · Controller (host) will send a not acknowledge bit
- · Controller (host) will send a stop bit

	Index Block F	Read O	peration
Cor	ntroller (Host)		IDT (Slave/Receiver)
Т	starT bit		
Slave	Address XX _(H)		
WR	WRite		
			ACK
Begi	nning Byte = N		
			ACK
RT	Repeat starT		
Slave	Address YY _(H)		
RD	ReaD		
			ACK
			Data Byte Count=X
	ACK		
			Beginning Byte N
	ACK		
		<u>e</u>	0
	0	X Byte	0
	0	×	0
	0		
			Byte N + X - 1
N	Not acknowledge		
Р	stoP bit		

SMBusTable: PLL Mode	e, and	Frequency	v Select	t Register

Byte	0	Pin #	Name	Control Function	Control Function Type 0 1		Default	
Bit 7	3 PLL Mode 1		PLL Mode 1	PLL Operating Mode Rd back 1	R	See PLL Operating Mode		Latch
Bit 6		3	PLL Mode 0	PLL Operating Mode Rd back 0	R	Readback Table		Latch
Bit 5		Reserved		1				
Bit 4	61/62 DIF_17_En		DIF_17_En	Output Control overrides OE# pin		Hi-Z	Enable	1
Bit 3	5	8/59	DIF_16_En	Output Control overrides OE# pin		Hi-Z	Enable	1
Bit 2				Reserved				0
Bit 1				Reserved				0
Bit 0		2	100M_133#	Frequency Select Readback	R	133MHz	100MHz	Latch

SMBusTable: Output Control Register

Byte	1 I	Pin #	Na	ame		Contro	I Function		Type	0		1	Default
Bit 7	34/	35	DIF	_7_En	0	utput Control	overrides OE#	# pin	RW				1
Bit 6	31/	32	DIF	_6_En	0	utput Control	overrides OE#	# pin	RW	Hi-Z		Enable	1
Bit 5			0	utput Control	overrides OE#	# pin	RW	TII-Z		Enable	1		
Bit 4	25/2	26	DIF	4_En	0	utput Control	overrides OE#	# pin	RW	<u> </u>			1
Bit 3							Reserved						1
Bit 2	22/	23	DIF	_2_En	0	utput Control	overrides OE#	# pin	RW				1
Bit 1	20/2	21	DIF	_1_En	0	utput Control	overrides OE#	# pin	RW	Hi-Z		Enable	1
Bit 0	17/	18	DIF	0_En	0	utput Control	overrides OE#	# pin	RW				1

SMBusTable: Output Control Register

Byte	yte 2 Pin # Name Control Function Type 0 1		1	Default				
Bit 7	7 56/57 DIF_15_En		DIF_15_En	Output Control overrides OE# pin	RW	Hi-Z	Enable	1
Bit 6				Reserved			1	
Bit 5	5	53/54	DIF_13_En	Output Control overrides OE# pin	RW			1
Bit 4	4	19/50	DIF_12_En	Output Control overrides OE# pin	RW	Hi-Z Enable		1
Bit 3		16/47	DIF_11_En	Output Control overrides OE# pin	RW	III-Z	Enable	1
Bit 2	4	13/44	DIF_10_En	Output Control overrides OE# pin	RW			1
Bit 1				Reserved				1
Bit 0	37/38 DIF_8_En Output Control overrides OE# pin RW Hi-Z Enable		Enable	1				

SMBusTable: Output Enable Pin Status Readback Register

Byte	3 Pin#	Name	Control Function	Туре		1	Default
Bit 7	51	OE_RB12	Real Time readback of OE#12	of OE#12 R			Real time
Bit 6	48	OE_RB11	Real Time readback of OE#11	R	OE# pin Low	OE# Pin High	Real time
Bit 5	45	OE_RB10	Real Time readback of OE#10	R			Real time
Bit 4			Reserved	•			0
Bit 3	39	OE_RB8	Real Time readback of OE#8	R			Real time
Bit 2	36	OE_RB7	Real Time readback of OE#7	R 05# min 1 avv		OF# Din High	Real time
Bit 1	33	OE_RB6	Real Time readback of OE#6	OE# pin Low OE# Pin			Real time
Bit 0	30	OE_RB5	Real Time readback of OE#5	R			Real time

SMBusTable: Reserved Register

Byte 4	Pin #	Name	Control Function	Type	0	1	Default		
Bit 7			Reserved						
Bit 6			Reserved				0		
Bit 5			Reserved						
Bit 4			Reserved						
Bit 3			Reserved						
Bit 2			Reserved						
Bit 1		Reserved							
Bit 0		Reserved							

SMBusTable: Vendor & Revision ID Register

Byte 5	5 Pin #	Name	Control Function	Type	0	1	Default
Bit 7	-	RID3		R			X
Bit 6	-	RID2	DEVISION ID	R	B rev	B rev = 0001	
Bit 5	-	RID1	REVISION ID		C rev = 0010		Х
Bit 4	-	RID0		R			X
Bit 3		VID3		R	-	-	0
Bit 2	-	VID2	VENDOR ID	R	-	-	0
Bit 1	-	VID1	VENDOR ID	R	-	-	0
Bit 0	-	VID0		R	-	-	1

SMBusTable: DEVICE ID

Byte	Byte 6 Pin # Name Control Function		Туре	0	1	Default	
Bit 7	-		Device ID 7 (MSB)	R			1
Bit 6	-		Device ID 6	R			1
Bit 5	-		Device ID 5	R	1		0
Bit 4	-		Device ID 4		Device ID is 219 decimal or		1
Bit 3	-		Device ID 3	R	DB	hex.	1
Bit 2	-		Device ID 2				0
Bit 1	-	Device ID 1		R			1
Bit 0	-		Device ID 0	R			1

SMBusTable: Byte Count Register

Byte	yte 7 Pin # Name		Control Function	Type	0	1	Default	
Bit 7			Reserved				0	
Bit 6			Reserved					
Bit 5		Reserved					0	
Bit 4	-	BC4		RW			0	
Bit 3	-	BC3	Writing to this register configures how	RW	Default value	is 8 hex, so 9	1	
Bit 2	-	BC2	many bytes will be read back.	RW	bytes (0 to 8) w	vill be read back	0	
Bit 1	-	BC1	many bytes will be read back.	RW	by de	efault.	0	
Bit 0	-	BC0		RW	•		0	

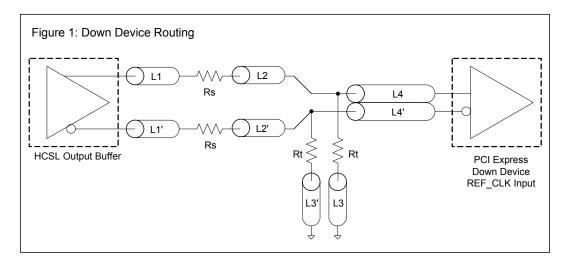
SMBusTable: Reserved Register

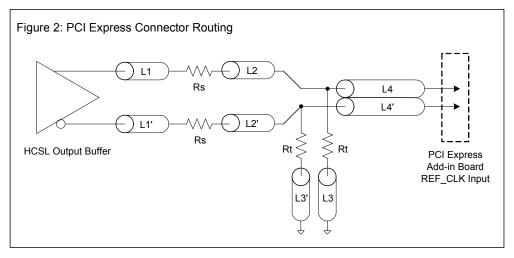
Byte 8	Pin #	Name	Control Function	Type	0	1	Default		
Bit 7			Reserved						
Bit 6			Reserved				0		
Bit 5			Reserved						
Bit 4			Reserved						
Bit 3			Reserved				0		
Bit 2			Reserved						
Bit 1		Reserved							
Bit 0			Reserved						

DIF Reference Clock							
Common Recommendations for Differential Routing	Dimension or Value	Unit	Figure				
L1 length, route as non-coupled 50ohm trace	0.5 max	inch	1				
L2 length, route as non-coupled 50ohm trace	0.2 max	inch	1				
L3 length, route as non-coupled 50ohm trace	0.2 max	inch	1				
Rs	33	ohm	1				
Rt	49.9	ohm	1				

Down Device Differential Routing			
L4 length, route as coupled microstrip 100ohm differential trace	2 min to 16 max	inch	1
L4 length, route as coupled stripline 100ohm differential trace	1.8 min to 14.4 max	inch	1

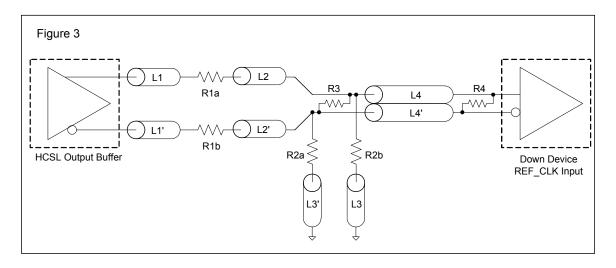
Differential Routing to PCI Express Connector			
L4 length, route as coupled microstrip 100ohm differential trace	0.25 to 14 max	inch	2
L4 length, route as coupled stripline 100ohm differential trace	0.225 min to 12.6 max	inch	2



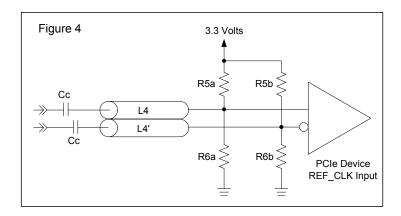


	Alternative Termination for LVDS and other Common Differential Signals (figure 3)							
Vdiff	Vp-p	Vcm	R1	R2	R3	R4	Note	
0.45v	0.22v	1.08	33	150	100	100		
0.58	0.28	0.6	33	78.7	137	100		
0.80	0.40	0.6	33	78.7	none	100	ICS874003i-02 input compatible	
0.60	0.3	1.2	33	174	140	100	Standard LVDS	

R1a = R1b = R1 R2a = R2b = R2



Cable Connected AC Coupled Application (figure 4)						
Component	Value	Note				
R5a, R5b	8.2K 5%					
R6a, R6b	1K 5%					
Cc	0.1 μF					
Vcm	0.350 volts					



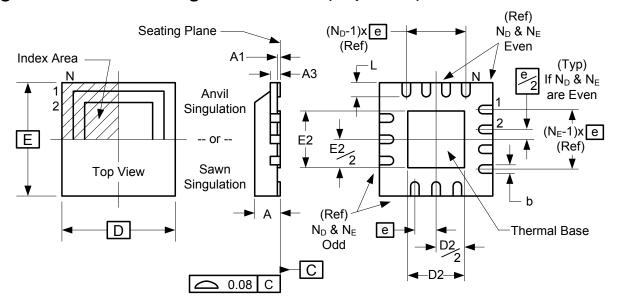
Marking Diagram



Notes:

- 1. "LOT" is the lot number.
- 2. "COO" is the country of origin.
- 2. "YYWW" is the last two digits of the year and week that the part was assembled.
- 3. "L" denotes RoHS compliant package.

Package Outline and Package Dimensions (64-pin MLF)



	Millimeters		
Symbol	Min	Max	
Α	0.8	1.0	
A1	0 0.05		
A3	0.25 Reference		
b	0.18 0.3		
е	0.50 BASIC		
D x E BASIC	9.00 x 9.00		
D2 MIN./MAX.	6.00	6.25	
E2 MIN./MAX.	6.00	6.25	
L MIN./MAX.	0.30	0.50	
N_D	16		
N _E	16		
N	64		

Ordering Information

Part / Order Number	Shipping Package	Package	Temperature
9ZX21501CKLF	Trays	64-pin MLF	0 to +70°C
9ZX21501CKLFT	Tape and Reel	64-pin MLF	0 to +70°C

[&]quot;LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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[&]quot;C" is the device revision designator (will not correlate with the datasheet revision).

Revision History

Rev.	Issue Date	Who	Description	Page #
Α	8/3/2010	RDW	Move to final.	
			1 Added note to pinout indicating that DFB_OUT pins need to be terminated identically	
В	5/11/2011	RDW	to normal DIF outputs.	2
С	12/8/2011	RDW	1. Updated tDSPO_BYP parameter from +/-350 to +/-250ps	7
D	12/15/2011	RDW	1. Lowered IDD3.3OP from MAX 500mA/TYP 407mA to MAX 425mA/ TYP 390mA	6
	12/10/2011	11211	2. Lowered IDD3.3PDZ from MAX36mA/TYP 12mA to MAX 15mA/ TYP 5mA	
F	4/23/2012	RDW	1. Updated Rp values on Output Terminations Table from 43.2 ohms to 42.2 or 43.2	9
	4/20/2012		ohms to be consistent with Intel.	J
F	F 4/16/2013	RDW	Corrected typo in OE# Latency parameter; changed 1 min. to 3 max. cycles to 4 min. to	6
'	4/10/2013	ווטעע	12 max. clocks	O

SYNTHESIZERS

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